



2SB1455/2SD2203

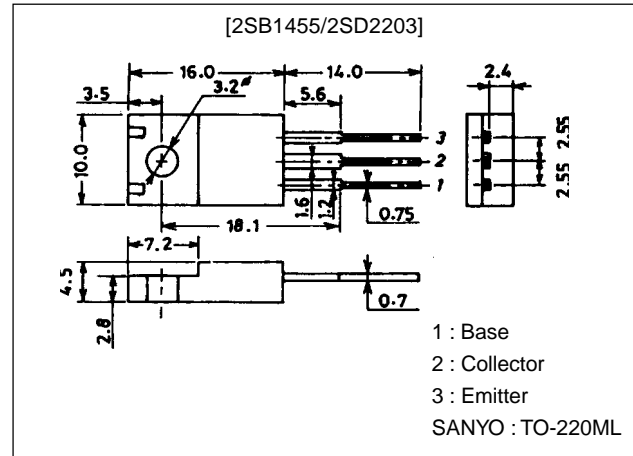
80V/7A High-Current Switching Applications

Features

- Low collector-to-emitter saturation voltage.
- Large current capacity.
- Micaless package facilitating easy mounting.

Package Dimensions

unit:mm
2041A



() : 2SB1455

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)90	V
Collector-to-Emitter Voltage	V_{CE0}		(-)80	V
Emitter-to-Base Voltage	V_{EB0}		(-)6	V
Collector Current	I_C		(-)7	A
Collector Current (Pulse)	I_{CP}		(-)12	A
Collector Dissipation	P_C		2.0	W
		$T_c=25^\circ\text{C}$	30	W
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)80\text{V}, I_E = 0$			(-)0.1	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4\text{V}, I_C = 0$			(-)0.1	mA
DC Current Gain	h_{FE1}	$V_{CE} = (-)2\text{V}, I_C = (-)1\text{A}$	70*		280*	
	h_{FE2}	$V_{CE} = (-)2\text{V}, I_C = (-)4\text{A}$	30			
Gain-Bandwidth Product	f_T	$V_{CE} = (-)5\text{V}, I_C = (-)1\text{A}$		20		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)4\text{A}, I_B = (-)0.4\text{A}$			0.4	V
					(-)0.5	V

* : The 2SB1455/2SD2203 are classified by 1A h_{FE} as follows :

70	Q	140	100	R	200	140	S	280
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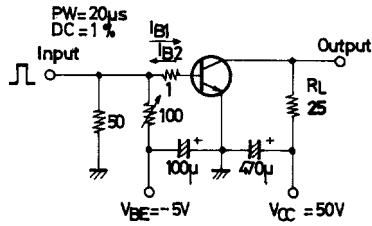
SANYO Electric Co., Ltd. Semiconductor Business Headquarters

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)1mA, I_E = 0$	(-)90			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)80			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)1mA, I_C = 0$	(-)6			V
Turn-ON Time	t_{on}	See specified test circuit.		(0.2)		μs
				0.1		μs
Storage Time	t_{stg}	See specified test circuit.		(0.7)		μs
				1.6		μs
Fall Time	t_f	See specified test circuit.		(0.2)		μs
				0.4		μs

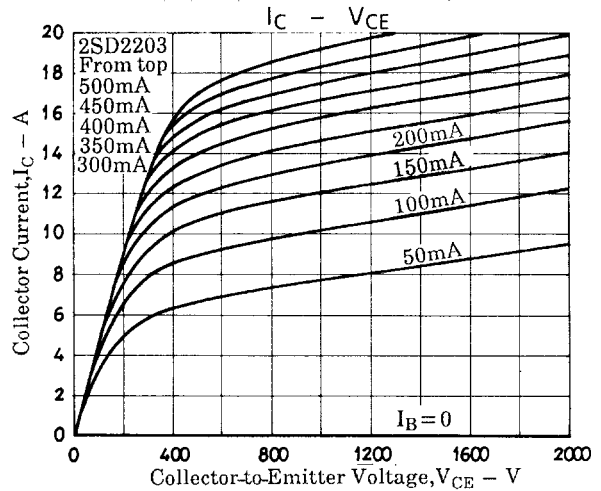
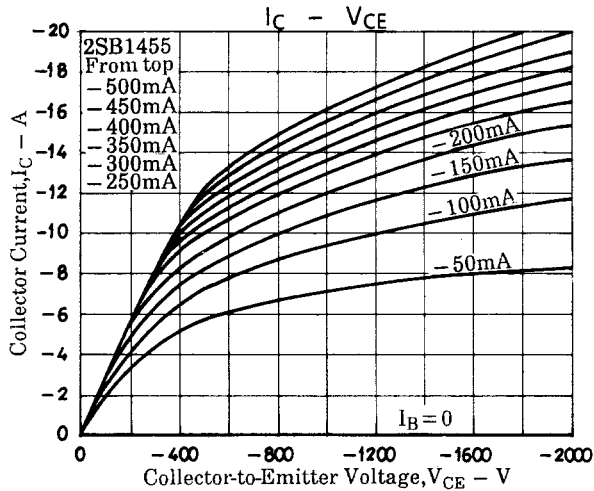
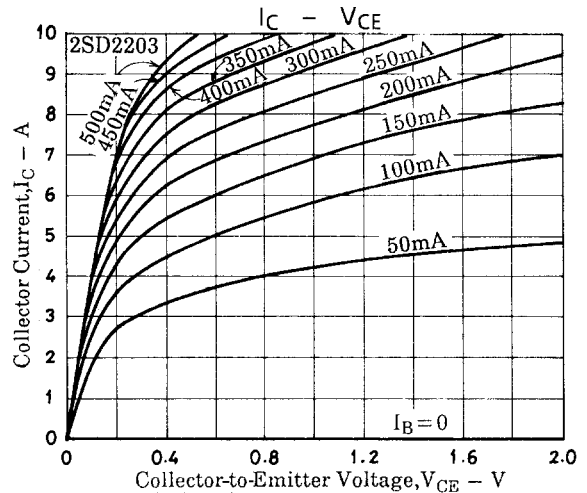
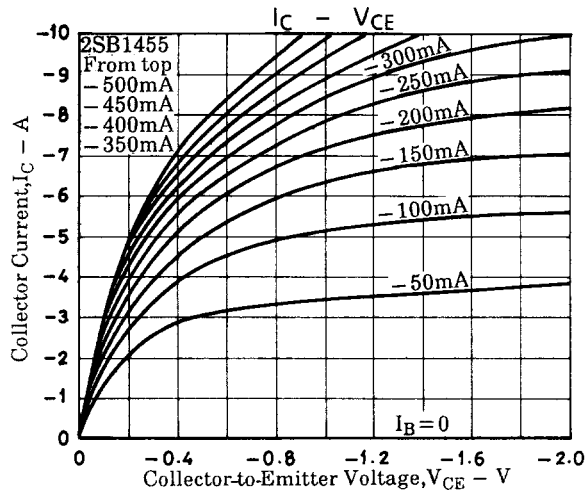
Switching Time Test Circuit



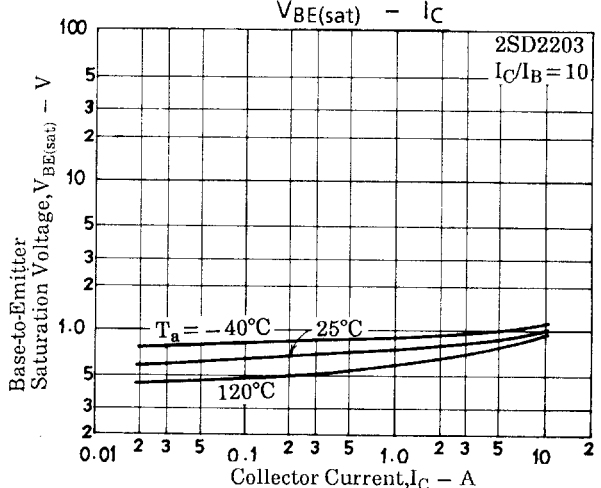
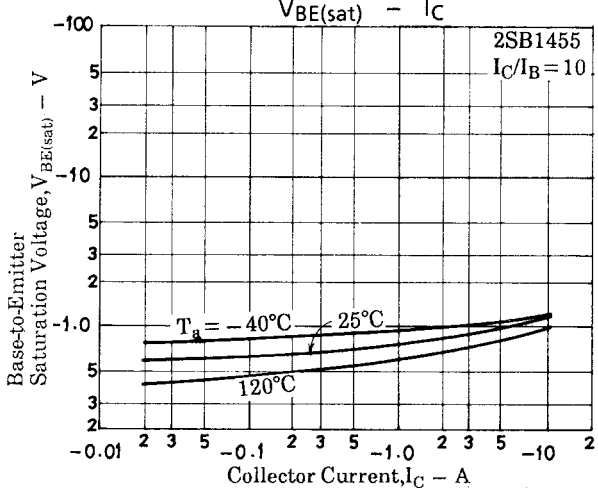
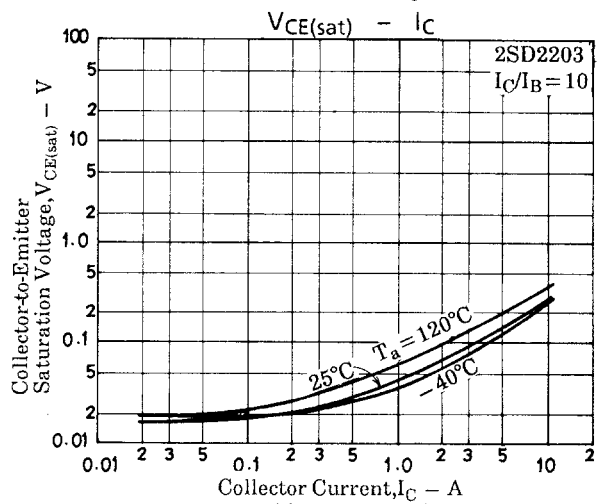
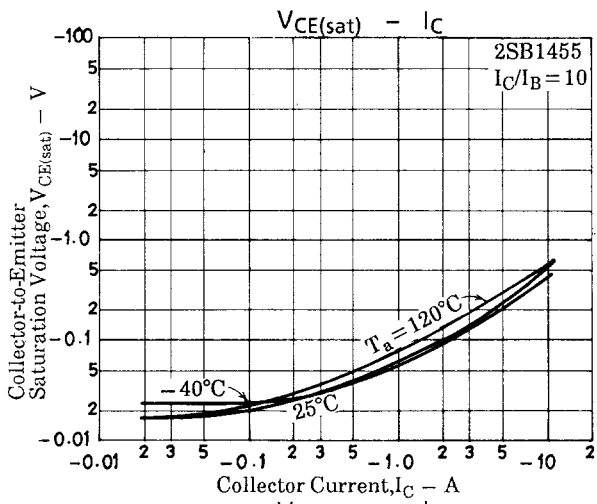
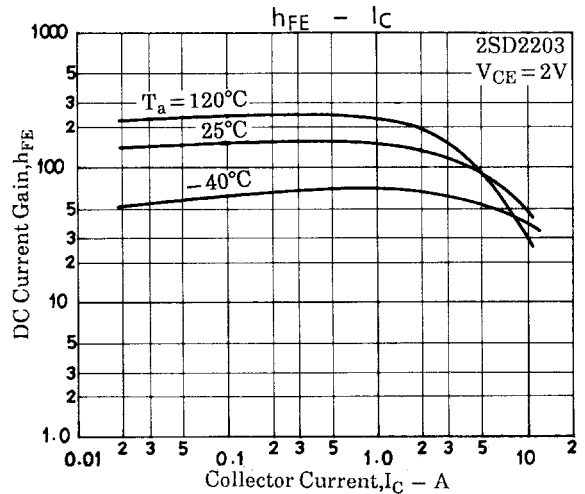
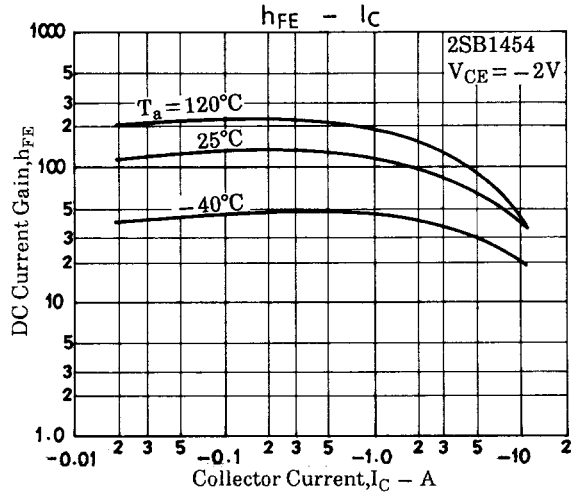
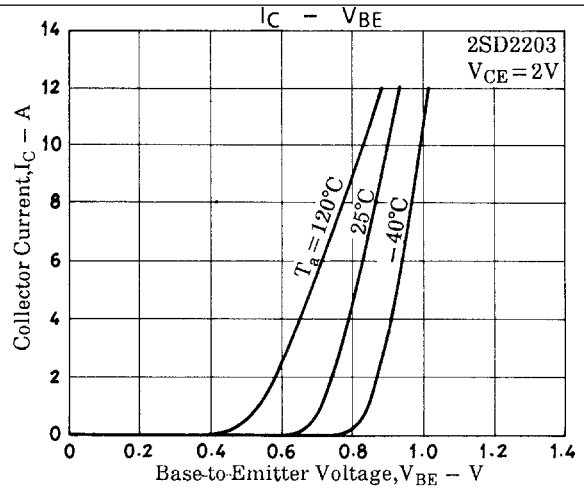
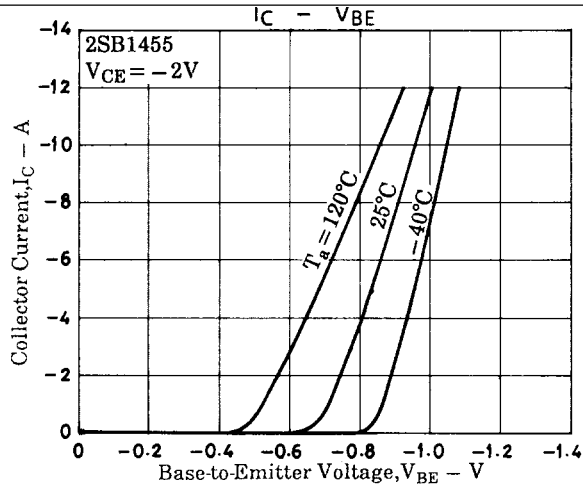
$10 I_{B1} = -10 I_{B2} = I_C = 2A$

For PNP, the polarity is reversed.

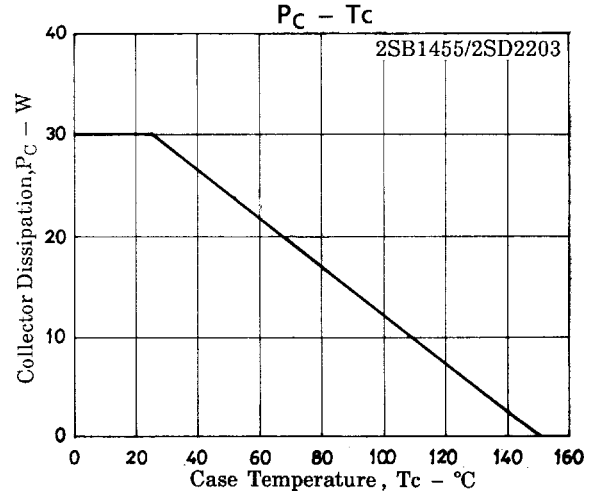
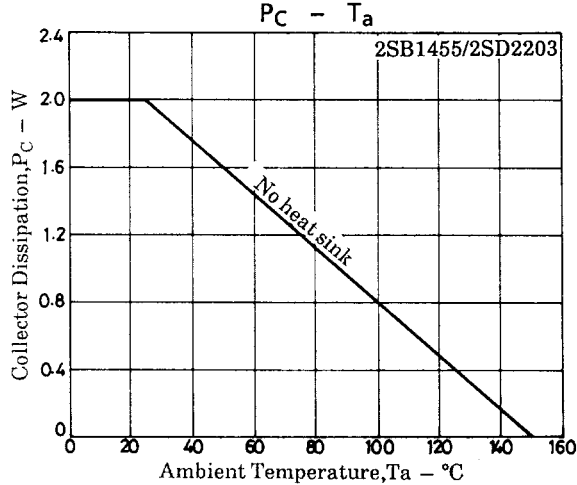
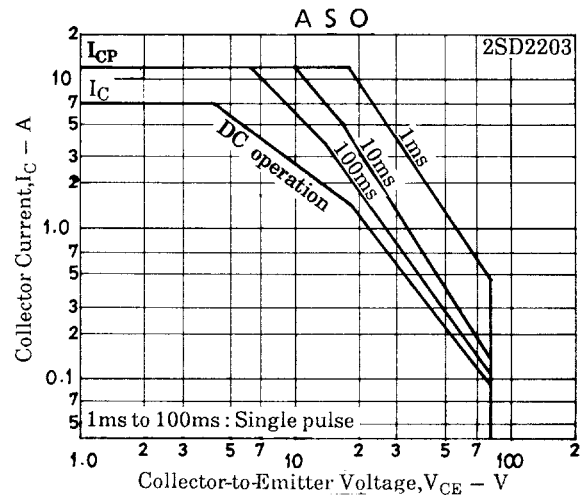
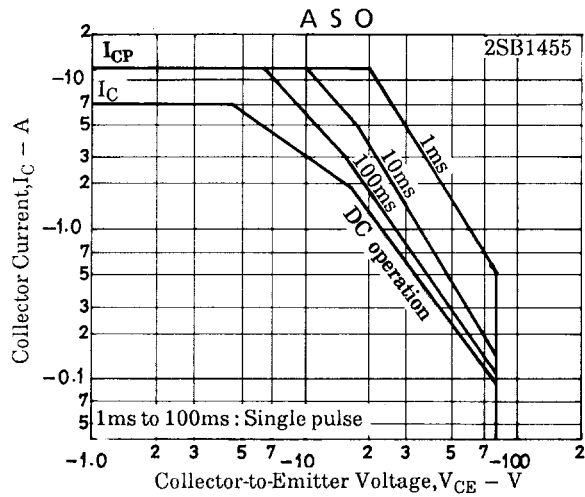
Unit (resistance : Ω , capacitance : F)



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